

STC4250F

NPN Silicon Transistor

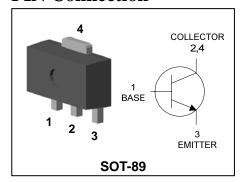
Applications

- Power amplifier application
- High current switching application

Features

- Low saturation voltage: $V_{CE(sat)}$ =0.15V Typ. @ I_C =1A, I_B =50mA
- Large collector current capacity: I_C=2A
 Small and compact SMD type package
- Complementary pair with STA3250F

PIN Connection



Ordering Information

Type NO.	Marking	Package Code
STC4250F	HW2 YWW	SOT-89

HW2: DEVICE CODE, YWW(Y: Year code, WW: Weekly code)

Absolute Maximum Ratings

[Ta=25℃]

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_{C}	2	А
Base current	${ m I}_{ m B}$	0.4	А
Collector Power dissipation	P _C	0.5	W
Collector Fower dissipation	P _C **	1	W
Junction temperature	T ₃	150	°C
Storage temperature range	T_{stg}	-55~150	°C

<sup>Medical Device mounted on ceramic substrate (250mm² x 0.8t)

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STC4250F

Electrical Characteristics

[Ta=25℃]

Charac	eteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-emitter b	oreakdown voltage	BV _{CEO}	I _C =10mA, I _B =0	50	-	1	٧
Collector cut-off cu	urrent	I _{CBO} V _{CB} =50V, I _E =0 (0.1	μА		
Emitter cut-off cur	rent	I_{EBO}	V _{EB} =5V, I _C =0	-	-	0.1	μА
DC current gain		h _{FE}	V _{CE} =2V, I _C =0.5A*	120	-	240	
DC current gain		h_{FE} $V_{CE}=2V$, $I_{C}=1.5A*$		40	-	ı	
Collector-emitter saturation voltage		$V_{\text{CE(sat)}}$	I _C =1A, I _B =0.05A*	1	-	0.35	V
Base-emitter satu	ration voltage	$V_{BE(sat)}$	I _C =1A, I _B =0.05A*	1	-	1.2	٧
Transition frequen	су	f_{T}	V _{CE} =2V, I _C =50mA	1	240	ı	MHz
Collector output ca	apacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz		15	-	pF
Switching Time	Turn-on Time	t _{on}	INPUT IBI OUTPUT	-	100	-	
	Storage Time	t _{stg}		-	300	-	nS
	Fall Time	t _f	Isi=- IRE=50mA 30V DUTY CYCLE ≤1%	-	50	1	

^{*:} Pulse test: $t_P \le 300 \mu s$, Duty cycle $\le 2\%$

Electrical Characteristic Curves

Fig. 1 $P_{\rm C}\,$ - T_a

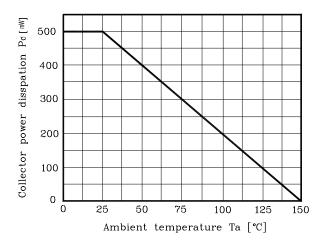


Fig. 3 I_C - V_{CE}

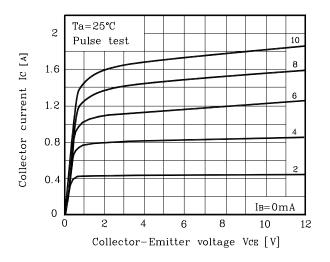


Fig. 5 $V_{\text{CE}(\text{sat})}$ - I_{C}

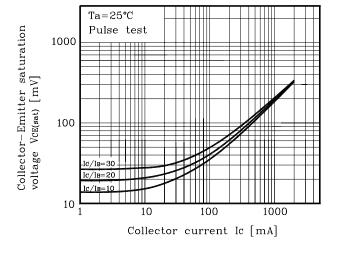


Fig. 2 $I_{C}\;$ - V_{BE}

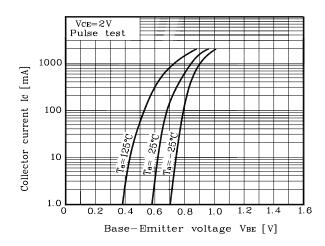


Fig. 4 h_{FE} - I_C

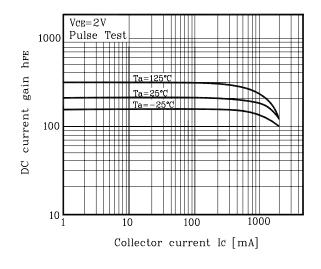
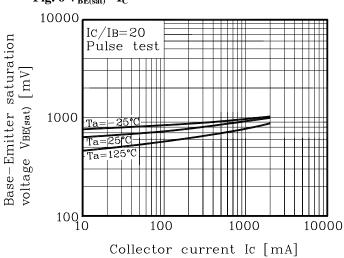


Fig. 6 $V_{BE(sat)}$ - I_{C}



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Electrical Characteristic Curves

Fig. 7 C_{Ob} - V_{CB}

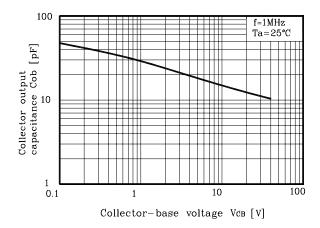
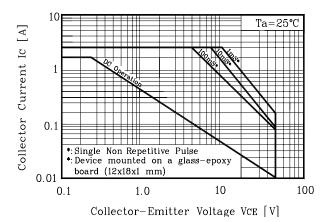
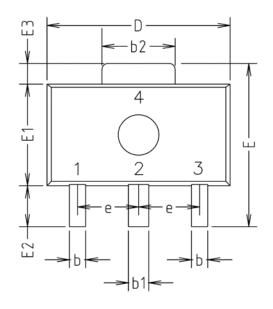
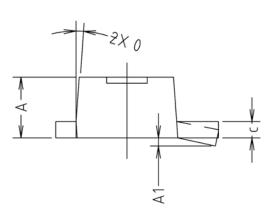


Fig. 8 Safe Operating Area



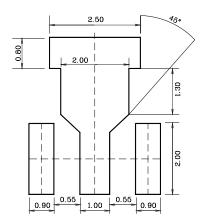
Outline Dimension(mm)





	MILLIMETERS			NOTE
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	ואטוב
Α	1.40	1.50	1.60	
A1	0.00	_	0.10	
b	0.38	0.42	0.48	
b1	0.48	0.52	0.58	
b2	1.79	1.82	1.87	
С	0.40	0.42	0.46	
D	4.40	4.50	4.70	
Ε	3.70	4.00	4.30	
E1	2.40	2.50	2.70	
E2	0.80	1.00	1.20	
E3	0.40	0.50	0.60	
е		1.50 TYP.		
0		4° TYP.		

***Recommend PCB solder land [Unit: mm]**



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